

Supporting Information for

Tuning Interface Bridging Between MoSe₂ and Three-Dimensional Carbon Framework by Incorporation of MoC Intermediate to Boost Lithium Storage Capability

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Supplementary Figures and Tables



Scheme S1 Schematic illustration of models of MoSe₂/C and MoSe₂/MoC/C heterostructure

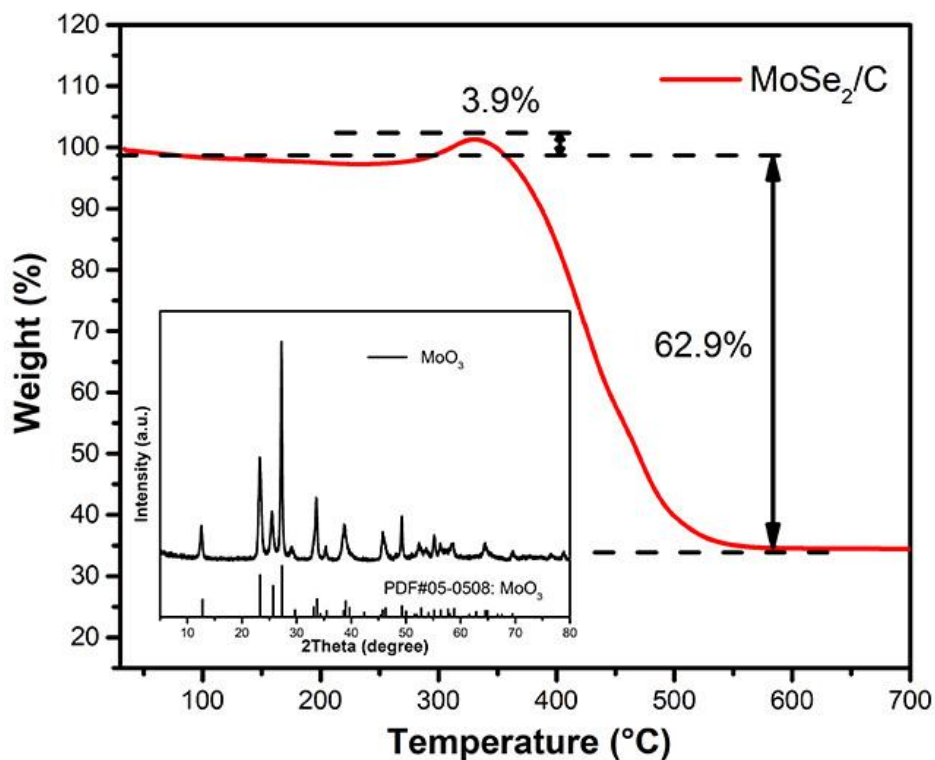
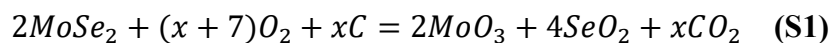


Fig. S1 TG curve of MoSe₂/C from room temperature to 700 °C at a heating rate of 10°C min⁻¹, the inset shows the XRD pattern of products after the TG test

During TG test, MoSe₂ oxidized to MoO₃ and SeO₂. And the reduced part is related to the leaving of SeO₂ and CO₂:



As a result, the carbon content of MoSe₂/C composite could be calculated as 34.6%.

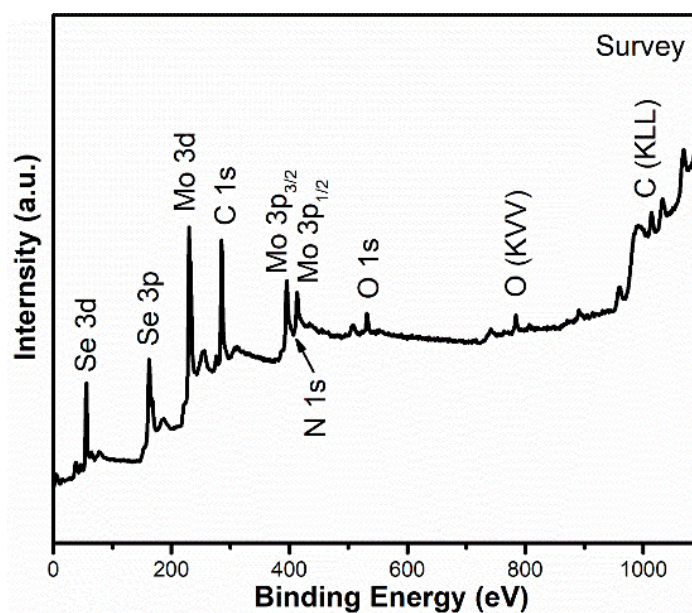


Fig. S2 XPS survey spectrum of MoSe₂/MoC@N-C sample

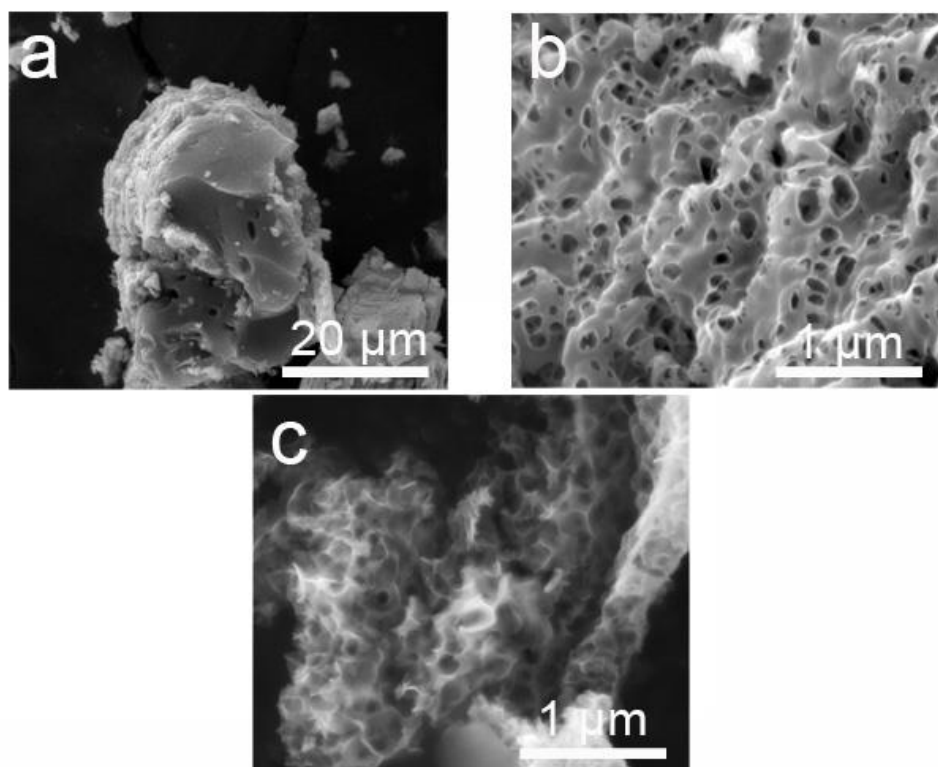


Fig. S3 SEM images (a) bare MoSe₂, (b) MoSe₂/C, and (c) MoSe₂/MoC@N-C

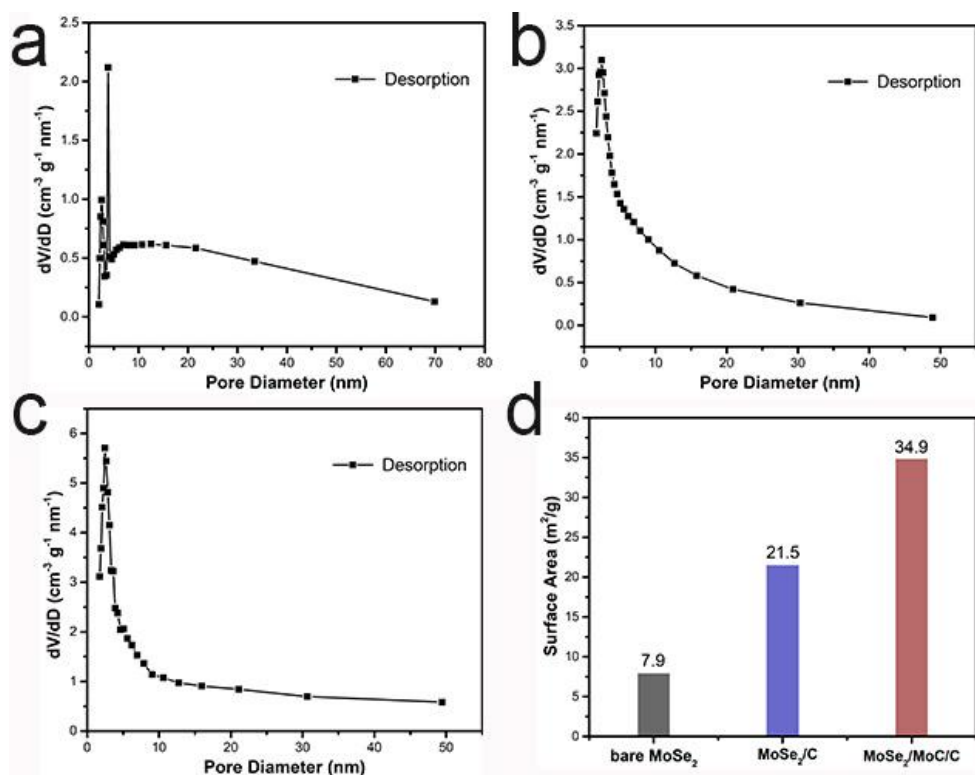


Fig. S4 Pore size distribution of three samples: (a) bare MoSe₂, (b) MoSe₂/C, (c) MoSe₂/MoC/C; (d) statistical figure of specific surface area of these three sample

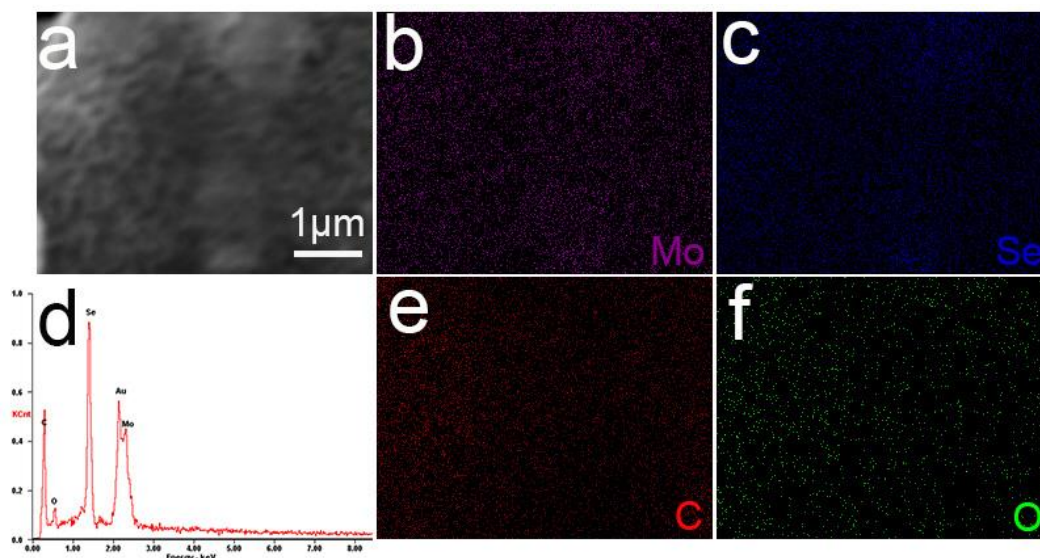


Fig. S5 EDS mapping of MoSe₂/MoC/N-C sample

Table S1 Elemental composition of MoSe₂/MoC/N-C from EDS mapping results

Elements	Atomic %	wt%
Se	4.87	17.66
Mo	2.66	11.73
C	83.4	45.92
O	6.9	5.06
Au	2.17	19.63

According to the elemental analysis result, the atomic ratio of Se to Mo is 1.831 in MoSe₂/MoC/N-C composite. For MoSe₂, the atomic ratio of Se to Mo is 2:1. The excess Mo can be attributed to MoC. Therefore, the molar ratio of MoSe₂ and MoC can be estimated as 54:5, and the mass ratio was calculated as 51:2.

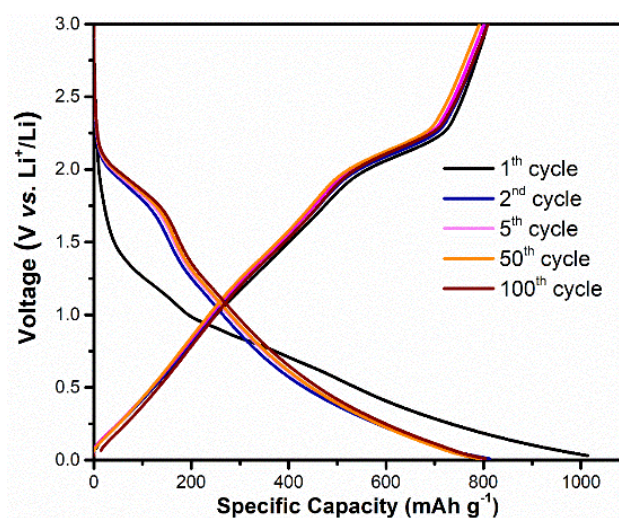


Fig. S6 Charge/discharge profiles of MoSe₂/MoC@N-C electrode at 0.1 A g⁻¹

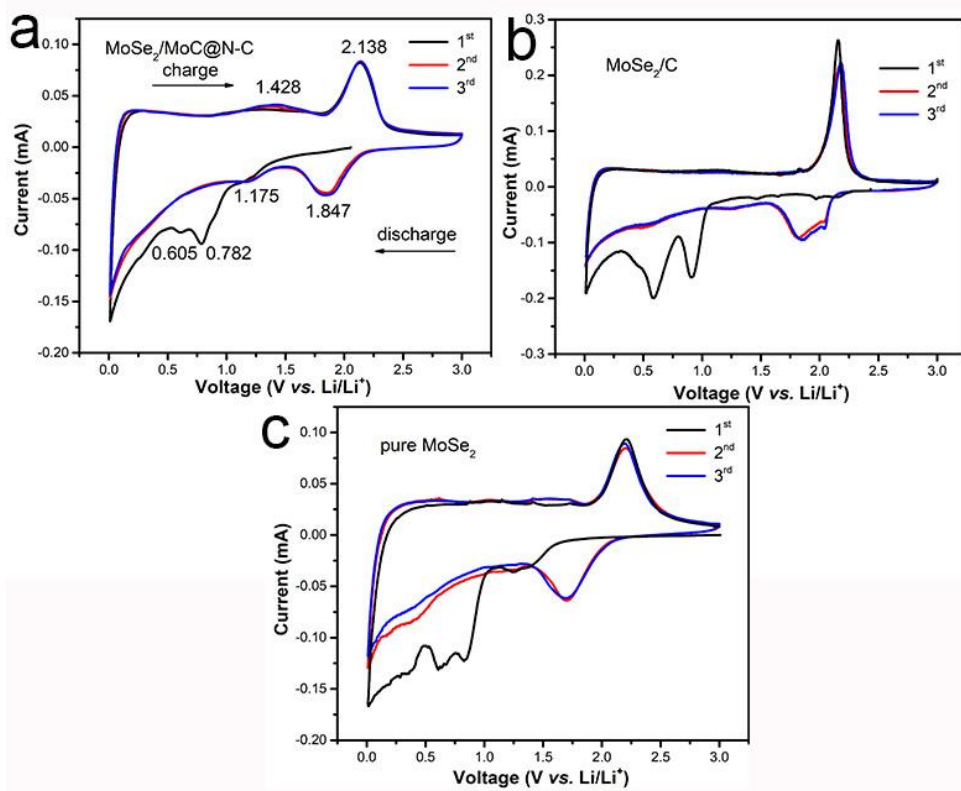


Fig. S7 First to third cyclic voltammograms of electrodes at a scan rate of 0.1 mV S^{-1} of (a) $\text{MoSe}_2/\text{MoC@N-C}$, (b) MoSe_2/C , and (c) bare MoSe_2

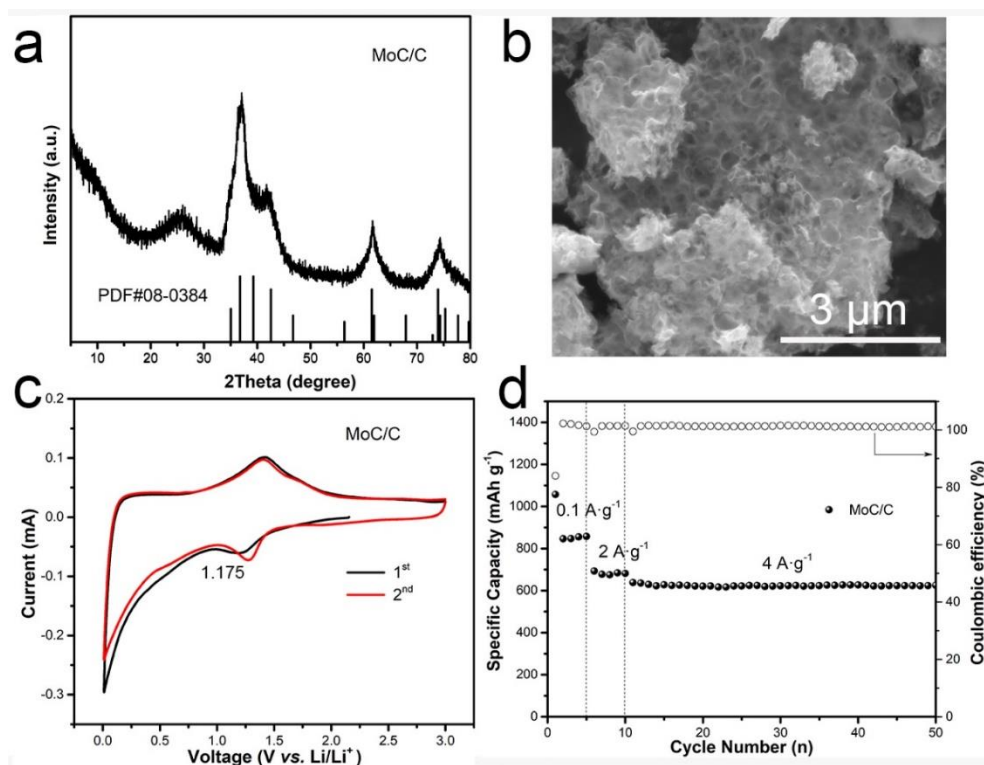


Fig. S8 XRD data (a) and SEM image (b) of MoC/C sample, (c) CV curves and (d) cycling performance of MoC/C electrode as anode of LIBs

Three dimensional porous MoC/C was synthesized by the similar method without Se powder. As shown in **Fig. S8a**, the XRD patterns exhibited several peaks matched well with MoC phase. The scanning electron microscopic (SEM) image (**Fig. S8b**) show that the morphologies of MoC/C was similar to the as-synthesized MoSe₂/MoC/C composites (**Fig. 2b**). To investigate the performance of MoC/C as anode for LIBs, CV and cycling test were conducted. As shown in **Fig. S8c**, the small peak at 1.175 V can be assigned to the reduction of MoC, and this peak almost remains constant in the second cycle, suggesting the reversible conversion reactions of MoC. These results are in good agree with that of CV curves of MoSe₂/MoC/N-C in **Fig. 3a**. **Figure S8d** shows the cycling performances of MoC/C sample at various current densities. MoC/C nanocomposite exhibits specific capacities of around 820, 640 and 590 mAh g⁻¹ at 0.1, 2.0 and 4.0 A g⁻¹, respectively, comparable to those of MoSe₂/MoC/N-C electrode (773, 622 and 575 mAh g⁻¹ at 0.1, 2.0 and 4.0 A g⁻¹, respectively).

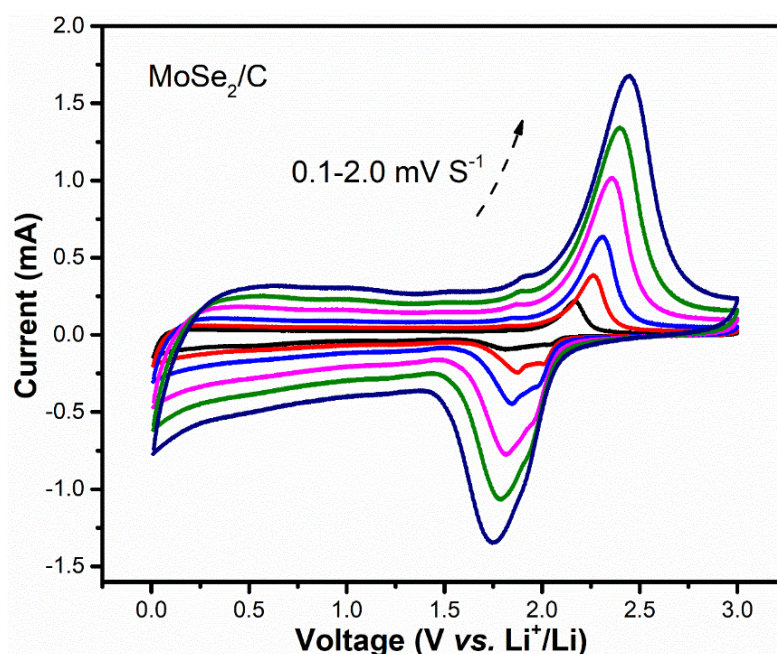


Fig. S9 CV curves at different scan rates of the MoSe₂/C electrode

The degree of capacitive effect can be qualitatively analyzed according to the relationship between measured current (i) and scan rate (v) from the CV curves [S1, S2]:

$$i = av^b = k_1v + k_2v^{1/2} \quad (\text{S2})$$

where a and b both are constants, v is the sweep rate (mV S⁻¹) and i (V) is the current (mA) at the corresponding sweep rate. The value of b is between 0.5 and 1.0, which is determined from the slope of the $\log i$ versus $\log v$ plot. It is well known that for a surface capacitance-dominated process b is close to 1.0, while a b -value of 0.5 signifies a solid-state diffusion-controlled reaction.

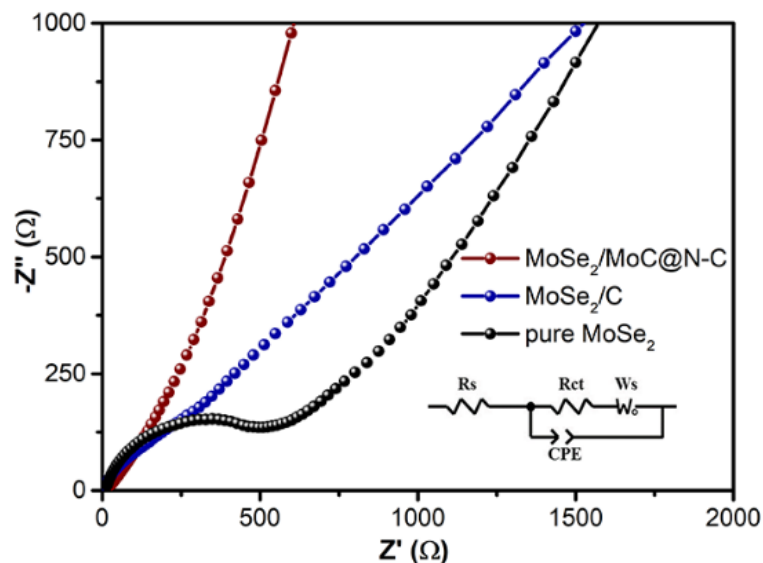


Fig. S10 Nyquist plots of pure MoSe₂, MoSe₂/C and MoSe₂/MoC@N-C electrodes after 1 cycle at 0.1 A g⁻¹, the inset shows the equivalent circuit. The semicircle in the medium-frequency band is related to the electrochemical reaction impedance, while the inclined line in the low frequency zone is related to the solid-state ion diffusion. The spectra are fitted by a classic equivalent circuit (the inset of **Fig. S10**), where R_{ct} is the charge-transfer resistance at the interfaces and Z_w is the Warburg impedance related to Li⁺ diffusions [S3].

Table S2 Fitting results of R_{ct} in equivalent circuit for Nyquist plots of **Fig. S8**

Samples	Bare MoSe ₂	MoSe ₂ /N-C	MoSe ₂ /MoC/N-C
R _{ct} (Ω)	557	72	43

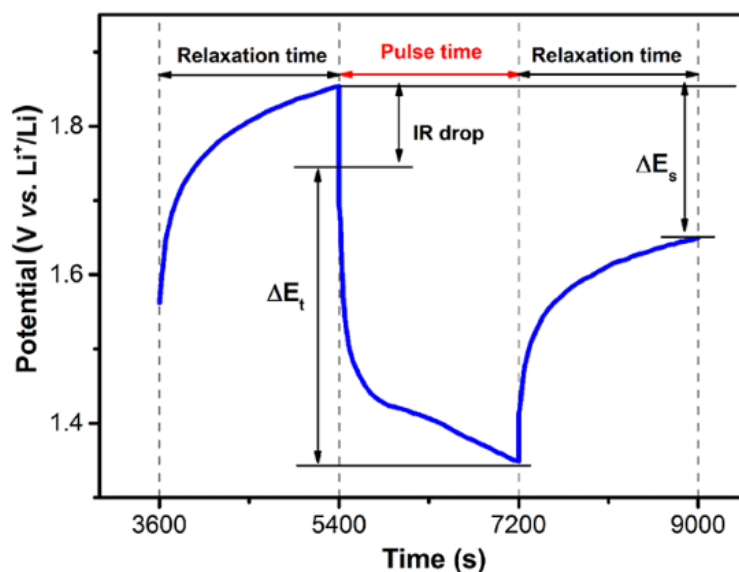


Fig. S11 E vs. t curves of MoSe₂/MoC@N-C electrode for a single GITT during discharge process

The lithium diffusion coefficient was measured by using Galvanostatic Intermittent Titration Technique (GITT) and calculated based on **Eq. S3** as follows [S3]:

$$D = \frac{4L^2}{\pi\tau} \left(\frac{\Delta E_s}{\Delta E t} \right)^2 \quad (\text{S3})$$

Where t is the duration of the current pulse (s), τ is the relaxation time (s), and ΔE_s is the steady-state potential change (V) by the current pulse. $\Delta E t$ is the potential change (V) during the constant current pulse after eliminating the iR drop. L is lithium ion diffusion length (cm); for compact electrode, it is equal to thickness of electrode.

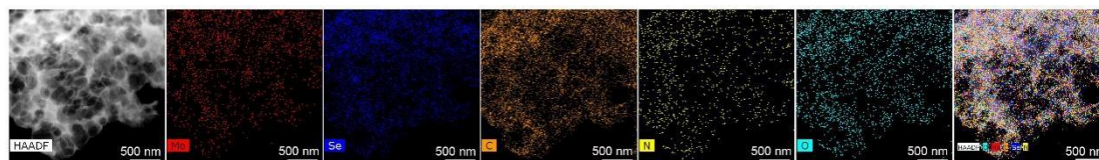


Fig. S12 Elemental mappings of MoSe₂/MoC/N-C

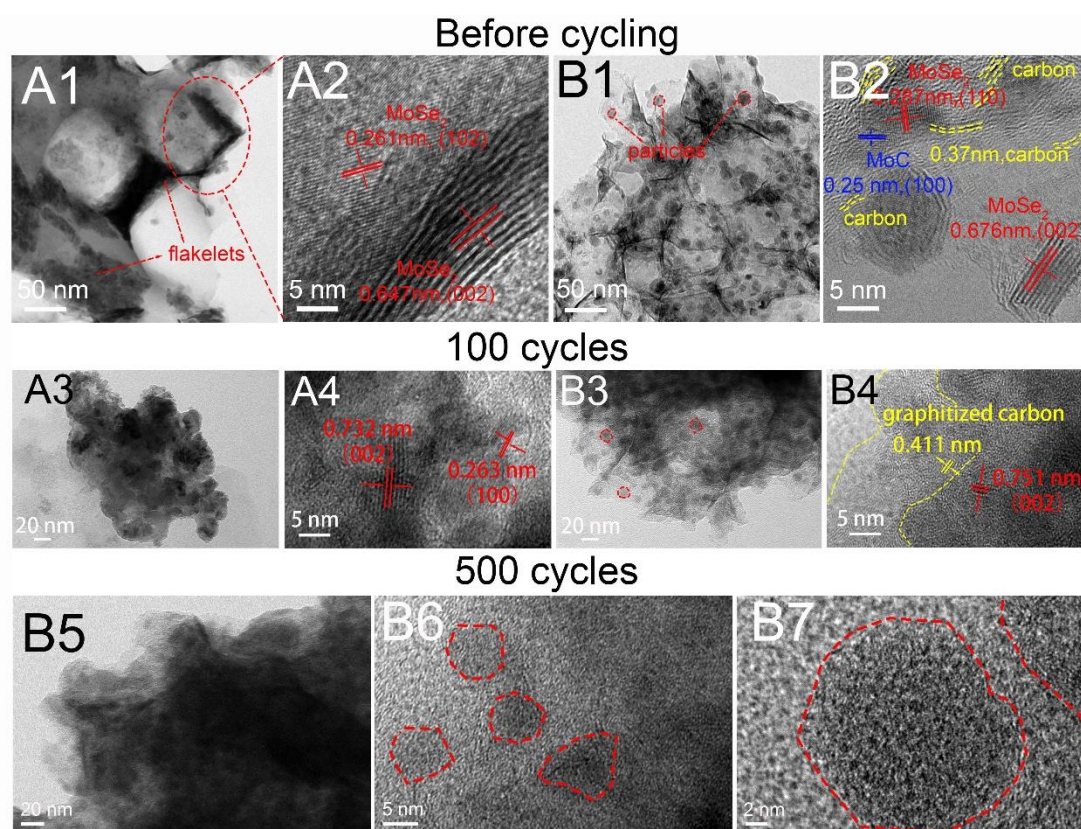


Fig. S13 *Ex-situ* TEM images of as prepared samples and electrodes after cycled at 2 A g⁻¹: (A1-A4) MoSe₂/N-C sample and corresponding electrode, (B1-B7) MoSe₂/MoC/N-C sample and corresponding electrode

Supplementary References

[S1] D. L. Chao, P. Liang, Z. Chen, L. Y. Bai, H. Shen et al., Pseudocapacitive Na-ion storage boosts high rate and areal capacity of self-branched 2d layered metal

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